L	Hits	Search Text	DB	Time stamp
Number				-
_	4	'gate oxide' and 'in-situ steam generation'	USPAT;	2003/08/22
		yelleracton	US-PGPUB; EPO; JPO;	07:29
ĺ			DERWENT;	
]	G-1: 20020210	IBM_TDB	
-	7	@ad<=20020219 and 'ONO' and 'in-situ steam generation' or 'ISSG'	USPAT;	2004/05/27
		steam deneration, of 1226.	US-PGPUB; EPO; JPO;	15:33
			DERWENT;	
			IBM TDB	
-	1	@ad<=20020219 and 'ONO' and 'ISSG'	USPAT;	2002/05/24
1		*	US-PGPUB; EPO; JPO;	08:28
			DERWENT;	
	1.0		IBM TDB	,
-	10	<pre>@ad<=20020219 and 'in-situ steam generation' or 'ISSG'</pre>	USPAT;	2002/05/24
		generation or issg.	US-PGPUB;	08:32
}			EPO; JPO; DERWENT;	5
			IBM TDB	
1 -	52	(438/954).CCLS.	USPĀT;	2002/05/24
			US-PGPUB;	13:24
			EPO; JPO; DERWENT;	
	· ·		IBM TDB	
-	245	(438/593).ccls. and @ad<=20020119	USPAT;	2002/05/24
			US-PGPUB;	13:26
			EPO; JPO; DERWENT;	
1			IBM TDB	
-·	627	(438/770).ccls. and @ad<=20020119	USPAT;	2002/05/24
İ			US-PGPUB;	13:31
			EPO; JPO; DERWENT;	
			IBM TDB	
Ī -	481	(438/264).ccls. and @ad<=20020119	USPAT;	2002/05/24
}	-8-		US-PGPUB;	13:27
'			EPO; JPO; DERWENT;	
1.1			IBM TDB	
-	. 208	(438/594).ccls. and @ad<=20020119	USPAT;	2002/05/24
			US-PGPUB; EPO; JPO;	13:27
	1	•	DERWENT;	
ļ	510		IBM TDB	. [
	518	(438/275).ccls. and @ad<=20020119	USPAT;	2004/05/27
[.]			US-PGPUB; EPO; JPO;	15:32
j l	l		DERWENT;	
- '	222	//20/100\	IBM_TDB	1
]	323	(438/199).ccls. and @ad<=20020119	USPAT;	2002/05/24
[US-PGPUB; EPO; JPO;	13:28
		•	DERWENT;	
<u> </u>	01	//20//77)1	IBM TDB	
-	91	(438/477).ccls. and @ad<=20020119	USPĀT;	2002/05/24
ļ . l			US-PGPUB; EPO; JPO;	13:28
			DERWENT;	
_	77	(420/016)1-	IBM_TDB	
_	77	(438/216).ccls. and @ad<=20020119	USPAT;	2002/05/24
			US-PGPUB; EPO; JPO;	13:28
			DERWENT;	
_	[]	(420/207)	IBM_TDB	
_	577	(438/287).ccls. and @ad<=20020119	USPAT;	2002/05/24
ł	ļ		US-PGPUB;	13:29
			EPO; JPO; DERWENT;	
			IBM TDB	
Search Hist		28/04 12:20:22 74		

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r			·		
	_	166	(438/783).ccls. and @ad<=20020119	USPAT;	2002/05/24
ı				US-PGPUB;	13:29
		1		EPO; JPO; DERWENT;	
			·	IBM TDB	
ł	_	8	I gase ontae and in Situ Steam	USPAT;	2002/10/16
			generation' or 'LP-RTP'	US-PGPUB;	10:36
				EPO; JPO;	
ı		1		DERWENT;	
- 1	- :	2	("5324675").PN.	IBM_TDB USPAT;	2002/10/16
				US-PGPUB;	2002/10/16
-		*		EPO; JPO;	-
				DERWENT;	
	-	1	'thin film transistor' and 'gate oxide'	IBM_TDB	
- 1			and 'in-situ steam generation' or	USPAT; US-PGPUB;	2002/10/16
		}	'LP-RTP'	EPO; JPO;	10:49
		1.		DERWENT;	
-		07016		IBM TDB	
	_	27216	@ad<=20020219 and 'TFT'	USPAT;	2002/10/16
- 1		1		US-PGPUB;	10:35
				EPO; JPO;	[
		1		DERWENT; IBM TDB	
	-	226	(and iloating	USPAT;	2002/10/16
1			gate'	US-PGPUB;	10:39
			·	EPO; JPO;	
.				DERWENT;	
-	-	169	(@ad<=20020219 and 'TFT') and 'oxide' and	IBM_TDB USPAT;	2002/10/16
			'floating gate'	US-PGPUB;	2002/10/16
			,	EPO; JPO;	10.55
1.		1	,	DERWENT;	
.	_	1	'tft' and 'in-situ steam generation' or	IBM_TDB	
		* 1	'LP-RTP'	USPAT;	2002/10/16
		ĺ		US-PGPUB; EPO; JPO;	11:12
				DERWENT;	
			10.1	IBM TDB	
		64	(@ad<=20020219 and 'TFT') and 'oxide layer' and 'floating gate'	USPAT;	2002/10/16
	-90		rayer and floating gate	US-PGPUB;	11:04
				EPO; JPO; DERWENT;	
:				IBM TDB	
-		571	(438/149).CCLS.	USPAT;	2002/10/16
		"		US-PGPUB;	11:05
İ			*	EPO; JPO;	
		1		DERWENT; IBM TDB	
-	-	11	@ad<=20020214 and (438/149).ccls. and	USPAT;	2002/10/16
		ĺ	'floating gate'	US-PGPUB;	11:06
	,	İ	7	EPO; JPO;	70
				DERWENT;	
-	.	3585	((438/294) or (438/954) or (438/593-594)	IBM_TDB USPAT;	2002/10/17
			or (438/770) or (438/264) or (438/275) or	US-PGPUB;	2002/10/17 09:50
ŀ			(438/199) or (438/477) or (438/216) or	EPO; JPO;	
]		(438/287) or (438/783)).CCLs.	DERWENT;	
_	. [15	@ad<=20020219 and 'ISSG'	IBM_TDB	2000 (00 (0
	ŀ		·	USPĀT; US-PGPUB;	2003/02/26 11:57
1	.	~		EPO; JPO;	11:3/
		1		DERWENT;	
_		. 29	Gad<=20020210 and Level	IBM_TDB	
		29	@ad<=20020219 and 'ONO' and 'in-situ steam generation' or 'ISSG'	USPAT;	2003/02/26
		1	goneracton of 1996.	US-PGPUB; EPO; JPO;	12:54
				DERWENT;	
_				IBM TDB	

-	27	@ad<=20020219 and 'ISSG'	USPAT;	2003/02/26
			US-PGPUB;	12:07
1			EPO; JPO;	1
ŀ			DERWENT;	
_	1 2	@ad<=20020219 and 'low pressure manid	IBM_TDB	
1	1	@ @ad<=20020219 and 'low pressure rapid thermal process'	USPAT;	2003/02/26
		chermal process	US-PGPUB;	12:17
	ł	· ·	EPO; JPO;	
1	ļ		DERWENT;	
-	416	@ad<=20020219 and 'TFT' and 'ONO'	IBM_TDB	0000 (00 (00
		and iii and ono	USPAT; ·US-PGPUB;	2003/02/27
			EPO; JPO;	07:12
		· ·	DERWENT;	
	Ĭ	•	IBM TDB	
	71		USPAT;	2003/08/22
		generation' or 'ISSG'	US-PGPUB;	08:16
	'	· ·	EPO; JPO;	00.10
	1		DERWENT;	1
_		(#650500 +#)	IBM TDB	
-	2	("6525384").PN.	USPAT;	2003/08/22
	i		US-PGPUB;	09:48
1			EPO; JPO;	
			DERWENT;	
i	2	"20030155582"	IBM_TDB	
	_	20030133382	USPAT;	2004/02/23
		*	US-PGPUB;	09:45
	i		EPO; JPO;	1
	1		DERWENT;	
	. 2	'TFT' and 'in-situ steam generation',	IBM_TDB USPAT;	2004 (00 (00
		generation , ,	US-PGPUB;	2004/02/23
			EPO; JPO;	10:04
		1	DERWENT;	
}			IBM TDB	
] -	2	("5700699").PN.	USPAT;	2004/02/23
			US-PGPUB;	09:59
			EPO; JPO;	
			DERWENT;	
i	1	ITEM and Is	IBM_TDB	
	_	'TFT' and 'free radical enhanced rapid thermal oxidation'	USPAT;	2004/02/23
		cheimai Oxidation	US-PGPUB;	10:32
		·	EPO; JPO;	
	•		DERWENT;	1
-	131	@ad<=20020219 and 'in-situ steam	IBM_TDB USPAT;	2004/05/07
1		generation' or 'ISSG'	US-PGPUB;	2004/05/27
ļ		· ·	EPO; JPO;	13.23
			DERWENT;	
1			IBM TDB	• .
-	121	@ad<=20020219 and 'SONOS' and 'in-situ	USPAT;	2004/05/27
		steam generation' or 'ISSG'	US-PGPUB;	13:34
i	İ		EPO; JPO;	
			DERWENT;	
_ [120	Mad<=20020210 and topyont	IBM_TDB	
	. 120	<pre>@ad<=20020219 and 'SONOS' same 'in-situ steam generation' or 'ISSG'</pre>	USPAT;	2004/05/27
		steam deneration, ot 1226.	US-PGPUB;	13:14
			EPO; JPO;	
			DERWENT;	
-]	. 1	@ad<=20020219 and 'SONOS device' same	IBM_TDB USPAT;	2004/05/27
1	1	'in-situ steam generation'	US-PGPUB;	2004/05/27
1	1	\$	EPO; JPO;	12:30
[DERWENT;	1
1	i		IBM TDB	
-	1	@ad<=20020219 and 'SONOS device' same	USPĀT;	2004/05/27
ĺ	ľ	'ISSG'	US-PGPUB;	12:31
	l		EPO; JPO;	
			DERWENT;	
			IBM TDB	

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	-	12:	- dan 20020213 and thin tilm transistor	USPAT;	2004/05/27	
- 1			same 'in-situ steam generation' or 'ISSG'	US-PGPUB;	13:16	
		,		EPO; JPO;		
			·	DERWENT; IBM TDB		
ļ	-	120		USPAT;	2004/05/27	
		İ	steam generation' or 'ISSG'	US-PGPUB;	13:17	
		1		EPO; JPO;	1 2 7 2 7	.
		· I		DERWENT;		ı
- [-	-	1	. @ad<=20020219 and 'TFT' and ('in-situ	IBM_TDB		l
1.		Į	steam generation' or 'ISSG')	USPAT; US-PGPUB;	2004/05/27	.
1	•	1		EPO; JPO;	13:17	
				DERWENT;		
١.	_	37	G-d20020010	IBM_TDB		
		3/	@ad<=20020219 and 'SONOS device'	USPAT;	2004/05/27	- 1
				US-PGPUB;	13:18	
ĺ				EPO; JPO; DERWENT;]
ł				IBM TDB		
· · -	- ,	2	1 and 1 and 20102 device and	USPAT;	2004/05/27	ĺ
ļ		1	'ISSG'	US-PGPUB;	13:18	
		1		EPO; JPO;		- 1
Ì	•			DERWENT;	**	-
-	-	1	"6319775".PN.	IBM_TDB USPAT	2004/25/25	
1				USPAT	2004/05/27	ſ
-		1	"6309927".PN.	USPAT	2004/05/27	
1_			W.C.D.O.D.O.D.W.		13:22	
-		1	"6309927".PN.	USPAT	2004/05/27	İ
-		1	"6248628".PN.		13:23	Í
			0240020 .FN.	USPAT	2004/05/27.	ļ
-	•	1	"6171900".PN.	USPAT	13:23 2004/05/27	- }
1				OSFAI	13:25	
~		1	@ad<=20020219 and 'in-situ steam	USPAT;	2004/05/27	ł
			generation' same 'SONOS' with 'device'	US-PGPUB;	13:26	
	e. •			EPO; JPO;		.]
				DERWENT; IBM TDB		1
-		1	louge and the steam	USPAT;	2004/05/27	İ
		1	generation' same 'SONOS'	US-PGPUB;	13:26	
-				EPO; JPO;	***	
	•,			DERWENT;		
-		3	@ad<=20020219 and 'SONOS' and 'in-situ	IBM_TDB	2224/25/25	
		1	steam generation'	USPAT; US-PGPUB;	2004/05/27 13:26	İ
		ļ ·		EPO; JPO;	13.20	- }
'	•	· .		DERWENT;		
_		2	@ad<=20020219 and 'SONOS' and 'ISSG'	IBM_TDB		
		-	cad = 20020219 and SUNOS' and 'ISSG'	USPAT;	2004/05/27	
		· ·	·	US-PGPUB; EPO; JPO;	13:27	- 1
ĺ				DERWENT;		}
			•	IBM TDB		ļ
-		1	@ad<=20020219 and 'TFT' and 'ISSG'	USPĀT;	2004/05/27	
		1	•	US-PGPUB;	13:27	1.
		*		EPO; JPO;		
	*]		DERWENT; IBM TDB		
-	0	39777	@ad<=20020219 and 'Thin film transistor'	USPAT;	2004/05/27	
				US-PGPUB;	13:29	
			İ	EPO; JPO;	- : - :	ĺ
]	·	DERWENT;		-
_		13	'SONOS' same 'device' and 'in-situ steam	IBM_TDB	0004/07/	
			generation'	USPAT; US-PGPUB;	2004/05/27	
				EPO; JPO;	13:44	
				DERWENT;		
				IBM TDB '	· ·	

-	14	'SONOS' and 'in-situ steam generation'	USPAT;	2004/05/27
			US-PGPUB;	13:45
	1		EPO; JPO;	120.10
			DERWENT;	
			IBM TDB	
-	3	'SONOS' and 'ISSG' with 'process'	USPAT;	2004/05/27
		•	US-PGPUB;	13:45
			EPO; JPO;	13.13
		*	DERWENT;	
		·	IBM TDB	1
ļ -	. 2	'TFT' and 'ISSG'	USPAT;	2004/05/27
			US-PGPUB;	13:45
	}		EPO; JPO;	13.13
			DERWENT;	
1.	ł		IBM TDB	
-	2	'TFT' and 'in-situ steam generation'	USPAT;	2004/05/27
	1		US-PGPUB;	13:45
			EPO; JPO;	
			DERWENT;	
·			IBM TDB	,
	238	@ad<=20020219 and 'bottom gate TFT'	USPAT;	2004/05/27
•	['	US-PGPUB;	15:32
			EPO; JPO;	'
	[DERWENT;]
			IBM TDB	
-] 1	@ad<=20020219 and 'tunnel oxide' same	USPAT;	2004/05/27
		'ISSG'	US-PGPUB;	15:34
		•	EPO; JPO;	
0			DERWENT;	·
			IBM TDB	